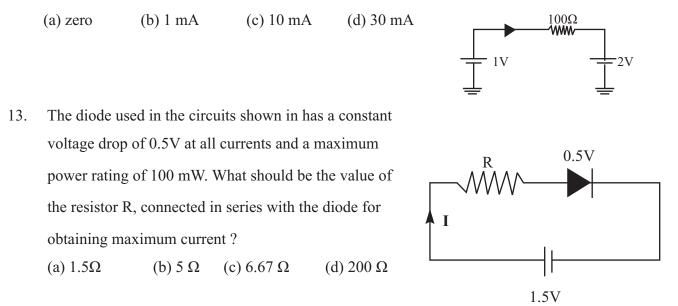
	· ·	ST. LAWRENCE HIGH SCHOOL				
AJI		WORK	ESUIT CHRISTIAN MINORITY INSTITUTION WORK SHEET: 48 Subject : PHYSICS			
CI		Subject			Date : 25.01. 2021	
	ASS : XII apter- Semiconductor	s and Electronics	characteristic	c curves, half a	verse bias diode, nd full wave	
			rectification.		1 X 15 = 15	
1	Multiple choice questions :1 X 15 = 15On increasing the reverse bias to a large value in a p-n junction diode current					
1.	-	-	1		1 1	
	(a) remains fixed	(b) increases slowly	y (c) suddenly incr	eases (d) d	ecreases slowly.	
2.	When a p - junction diode is forward biased, potential barrier					
	(a) remains same	(b) decreases	(c) increases	(d) may in	ncrease or decrease	
3.	In a half-wave rect	ifier. The r.m.s. value of	the ac component of the	e wave is		
2.	In a half-wave rectifier, The r.m.s. value of the ac component of the wave is (a) equal to dc value (b) more than dc value (c) less than dc value (d) zero.					
	(,) - 1		()			
4.	P N Junction diode	is reverse biased then				
	(a) the barrier poter	ntial decreases		(b) barrier potential increases		
	(c) more current flows			(d) resistance offered is low		
5.	In intrinsic semi-conductor at room temperature number of electrons and holes are					
	(a) equal	(b) zero	(c) unequal		nfinite	
6.	A rectifier converts					
0.			(h) light energy t	o electrical energy	
	(a) mechanical energy to electrical energy(c) ac to dc			(b) light energy to electrical energy(d) none of these		
	Ans. (c) ac to dc					
7.	In the middle of the depletion layer of a reverse biased p - n juction, the					
	(a) electric field is zero		(b) potential is m	(b) potential is maximum		
	(c) electric field is maximum		(d) potential is z	(d) potential is zero		
8.	The potential barrie	er, in the depletion layer,	is due to			
	(a) ions	(b) electrons	(c) holes	(d) forb	idden band	

- 9. When plate voltage in a diode valve is increases from 100 V to 150 V, then plate current increases rom 7.5 mA to 12 mA. The dynamic plate resistance will be
 (a) 10 kΩ
 (b) 11 kΩ
 (c) 15 kΩ
 (d) 11.1 kΩ
- In a full wave rectifier with input frequency 50 Hz. The ripple in the output is mainly of the frequency (in Hz)

(a) 25 (b) 50 (c) 100 (d) none of these

11. A half-wave rectifier is being used to rectify an alternating voltage of frequency 50 Hz. The number of pulses of rectified current obtained in one second is
(a) 50 (b) 25 (c) 100 (d) 200

12. Assuming that the junction diode is ideal in the circuit shown in the current through the diode is



14. In forward bias the width of potential barrier in a *p*-*n* junction diode
(a) increases
(b) decreases
(c) remain constant
(d) first (a) then (b)

15. In a junction diode, the holes are due to

(a) protons (b) neutrons (c) extra electrons (d) miss	ing of electrons.
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